Claim Amendments

Amend the claims as follows:

1 – 15 (Canceled)

16. (New) A solar cell module comprising:

a solar cell element;

a light incidence side light transmitting member made of a glass adhered at a light incidence side of the solar cell element by a resin; and

a rear surface member comprising a resin film adhered at a rear surface side of the solar cell element by a resin, wherein

the solar cell element comprises a semiconductor junction so as to form an electric field and is sealed with each of the resin adhering the light incidence side light transmitting member and the rear surface member,

the resin for adhering the light incidence side light transmitting member at the light incidence side of the solar cell element contains a sodium ion depositing from the light incidence side light transmitting member, and

the solar cell element comprises a one conductive type crystalline semiconductor substrate between the semiconductor junction and the resin containing the sodium ion so as to shield a diffusion of sodium ion to the semiconductor junction.

17. (New) The solar cell module according to claim 16, wherein

the resin for adhering the light incidence side light transmitting member at the light incidence side of the solar cell element has a sodium ion content of at least 0.3 μg/g.

18. (New) The solar cell module according to claim 16, wherein

the one conductive type crystalline semiconductor substrate consists of a single crystalline silicon and has a thickness so as to shield the diffusion of sodium ion.

19. (New) The solar cell module according to claim 16, further comprising:
a one conductive type semiconductor layer between the one conductive type crystalline semiconductor substrate and the resin containing the sodium ion.

20. (New)The solar cell module according to claim 19, further comprising:
a transparent electrode between the one conductive type semiconductor layer and the resin containing the sodium ion.

21. (New)The solar cell module according to claim 19, further comprising:
an anti-reflection layer between the one conductive type semiconductor layer and the resin containing the sodium ion.

22. (New) The solar cell module according to claim 16, wherein
the semiconductor junction is formed by the one conductive type crystalline semiconductor substrate and an another conductive type crystalline semiconductor.

23. (New) The solar cell module according to claim 16, wherein
the semiconductor junction is formed by the one conductive type crystalline semiconductor substrate and an another conductive type amorphous semiconductor.

24. (New) The solar cell module according to claim 23, comprising:
an intrinsic amorphous semiconductor between the one conductive type crystalline semiconductor substrate and the another conductive type amorphous semiconductor.

25. (New) The solar cell module according to claim 19, wherein
the one conductive type semiconductor layer is formed by a crystalline semiconductor.

26. (New) The solar cell module according to claim 19, wherein

the one conductive type semiconductor layer is formed by an amorphous semiconductor.

27. (New) The solar cell module according to claim 26, wherein

an intrinsic amorphous semiconductor is comprised between the one conductive type crystalline semiconductor substrate and the one conductive type crystalline semiconductor substrate.